

## Key Features :

- Frequency range : 0-40GHz
- Insertion loss: 3dB
- Input/output standing wave :1.1
- Chip dimensions : $0.7 \mathrm{~mm} \times 0.7 \mathrm{~mm} \times 0.1 \mathrm{~mm}$
- Applications : wireless communication, transceiver module, radio telecommunication etc.


## Description :

AMT1624 is a high performance fixed attenuator chip, it is designed by Gallium Arsenide (GaAs) pHEMT process. It covers frequency range of DC -40 GHz , attenuation is 3 dB . This chip is designed with ground through metal vias on the back technology. All chip products p are $100 \%$ RF tested.

| Absolute Maximum Ratings $\left(\mathbf{T a}=\mathbf{2 5}{ }^{\circ} \mathrm{C}\right)$ | Value | Remark |  |
| :---: | :---: | :---: | :---: |
| Symbol | Parameter | 30 dBm |  |
| Pin | Input Power | $290^{\circ} \mathrm{C}$ | $30 \mathrm{~s}, \mathrm{~N}_{2}$ protection |
| Tm | Sintering Temperature | $-65 \sim+150^{\circ} \mathrm{C}$ |  |
| Tstg | Storage Temperature |  |  |

[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.
Electrical Characteristics ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Symbol | Parameter | Value |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typical | Max |  |
| VSWRin | Input Standing Wave | - | 1.1 | 1.3 | - |
| VSWRout | Output Standing Wave | - | 1.1 | 1.3 | - |
| IL | Insertion Loss | - | 3 | - | dB |

## Typical Performance




Chip Dimensions (Unit : $\mu \mathrm{m}$ )


## Chip Layout Diagram



Please see Appendix A for details.

